FAIRCHILD SEMICONDUCTOR™

March 1988
Revised January 2004

74F646
Octal Transceiver/Register with 3-STATE Outputs

General Description

These devices consist of bus transceiver circuits with 3-STATE, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to a high logic level. Control $\overline{G}$ and direction pins are provided to control the transceiver function. In the transceiver mode, data present at the high impedance port may be stored in either the A or the B register or in both. The select controls can multiplex stored and real-time (transparent mode) data. The direction control determines which bus will receive data when the enable control $\overline{G}$ is Active LOW. In the isolation mode (control $\overline{G}$ HIGH), A data may be stored in the B register and/or B data may be stored in the A register.

Features

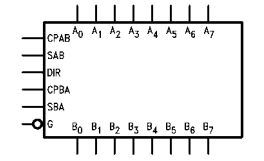
- Independent registers for A and B buses
- Multiplexed real-time and stored data
- 74F646 has non-inverting data paths
- 3-STATE outputs
- 300 mil slim DIP

Ordering Code:

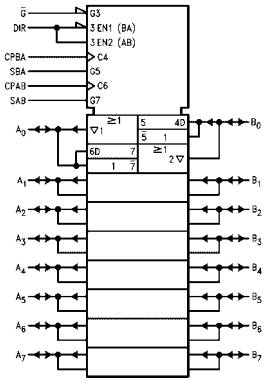
Order Number	Package Number	Package Description
74F646SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74F646MSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), JEDEC MO-150, 5.3mm Wide
74F646SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

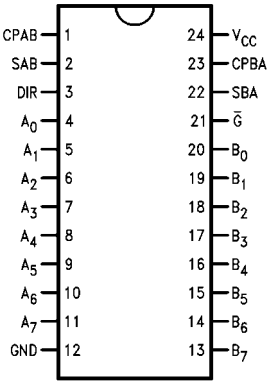
Logic Symbols



IEEE/IEC



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
A_0–A_7	Data Register A Inputs/	3.5/1.083	70 µA/–650 µA
	3-STATE Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)
B_0–B_7	Data Register B Inputs/	3.5/1.083	70 µA/–650 µA
	3-STATE Outputs	600/106.6 (80)	–12 mA/64 mA (48 mA)
CPAB, CPBA	Clock Pulse Inputs	1.0/1.0	20 µA/–0.6 mA
SAB, SBA	Select Inputs	1.0/1.0	20 µA/–0.6 mA
$\overline{G}$	Output Enable Input	1.0/1.0	20 µA/–0.6 mA
DIR	Direction Control Input	1.0/1.0	20 µA/–0.6 mA

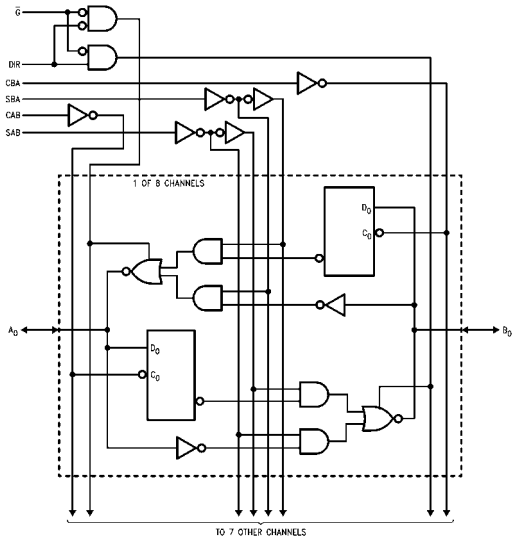
Function Table

Inputs						Data I/O (Note 1)		Function
$\overline{G}$	DIR	CPAB	CPBA	SAB	SBA	A_0–A_7	B_0–B_7	
H	X	H or L	H or L	X	X	Input	Input	Isolation
H	X	↑	X	X	X			Clock A_n Data into A Register
H	X	X	↑	X	X			Clock B_n Data into B Register
L	H	X	X	L	X	Input	Output	A_n to B_n—Real Time (Transparent Mode)
L	H	↑	X	L	X			Clock A_n Data into A Register
L	H	H or L	X	H	X			A Register to B_n (Stored Mode)
L	H	↑	X	H	X			Clock A_n Data into A Register and Output to B_n
L	L	X	X	X	L	Output	Input	B_n to A_n—Real Time (Transparent Mode)
L	L	X	↑	X	L			Clock B_n Data into B Register
L	L	X	H or L	X	H			B Register to A_n (Stored Mode)
L	L	X	↑	X	H			Clock B_n Data into B Register and Output to A_n

H = HIGH Voltage Level L = LOW Voltage Level X = Irrelevant ↑ = LOW-to-HIGH Transition

Note 1: The data output functions may be enabled or disabled by various signals at the $\overline{G}$ and DIR Inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the clock inputs.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 2)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 3)	−0.5V to +7.0V
Input Current (Note 3)	−30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
3-STATE Output	−0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Recommended Operating Conditions

Free Air Ambient Temperature	0°C to +70°C
Supply Voltage	+4.5V to +5.5V

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I_{IN} = −18 mA (Non I/O Pins)
V_{OH}	Output HIGH 10% V_{CC} Voltage	2.0			V	Min	I_{OH} = −15 mA (A_n, B_n)
V_{OL}	Output LOW 10% V_{CC} Voltage			0.55	V	Min	I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current			5.0	µA	Max	V_{IN} = 2.7V (Non I/O Pins)
I_{BVI}	Input HIGH Current Breakdown Test			7.0	µA	Max	V_{IN} = 7.0V (Non I/O Pins)
I_{BVIT}	Input HIGH Current Breakdown (I/O)			0.5	mA	Max	V_{IN} = 5.5V (A_n, B_n)
I_{CEX}	Output HIGH Leakage Current			50	µA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current			3.75	µA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current			−0.6	mA	Max	V_{IN} = 0.5V (Non I/O Pins)
I_{IH} + I_{OZH}	Output Leakage Current			70	µA	Max	V_{OUT} = 2.7V (A_n, B_n)
I_{IL} + I_{OZL}	Output Leakage Current			−650	µA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current	−100		−225	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test			500	µA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			135	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			150	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			150	mA	Max	V_O = HIGH Z

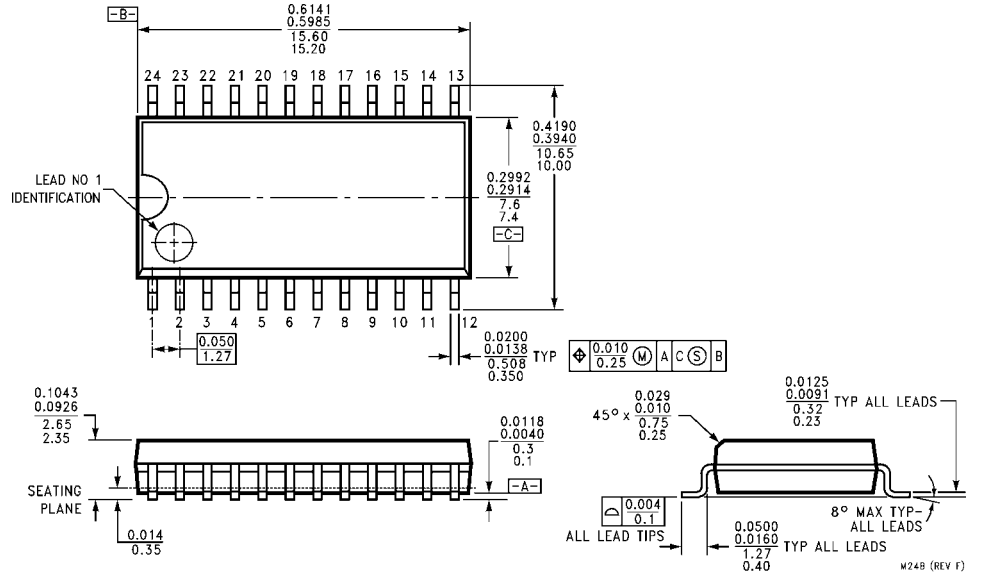
AC Electrical Characteristics

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF		Units
		Min	Max	Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	90		75		90		MHz
t_{PLH}	Propagation Delay	2.0	7.0	2.0	8.5	2.0	8.0	ns
t_{PHL}	Clock to Bus	2.0	8.0	2.0	9.5	2.0	9.0	
t_{PLH}	Propagation Delay	1.0	7.0	1.0	8.0	1.0	7.5	ns
t_{PHL}	Bus to Bus	1.0	6.5	1.0	8.0	1.0	7.0	
t_{PLH}	Propagation Delay	2.0	8.5	2.0	11.0	2.0	9.5	ns
t_{PHL}	SBA or SAB to A or B	2.0	8.0	2.0	10.0	2.0	9.0	
t_{PZH}	Enable Time	2.0	8.5	2.0	10.0	2.0	9.0	ns
t_{PZL}	$\overline{OE}$ to A or B	2.0	12.0	2.0	13.5	2.0	12.5	
t_{PHZ}	Disable Time	1.0	7.5	1.0	9.0	1.0	8.5	ns
t_{PLZ}	$\overline{OE}$ to A or B	2.0	9.0	2.0	11.0	2.0	9.5	
t_{PZH}	Enable Time	2.0	14.0	2.0	16.0	2.0	15.0	ns
t_{PZL}	DIR to A or B	2.0	13.0	2.0	15.0	2.0	14.0	
t_{PHZ}	Disable Time	1.0	9.0	1.0	10.0	1.0	9.5	ns
t_{PLZ}	DIR to A or B	2.0	11.0	2.0	12.0	2.0	11.5	

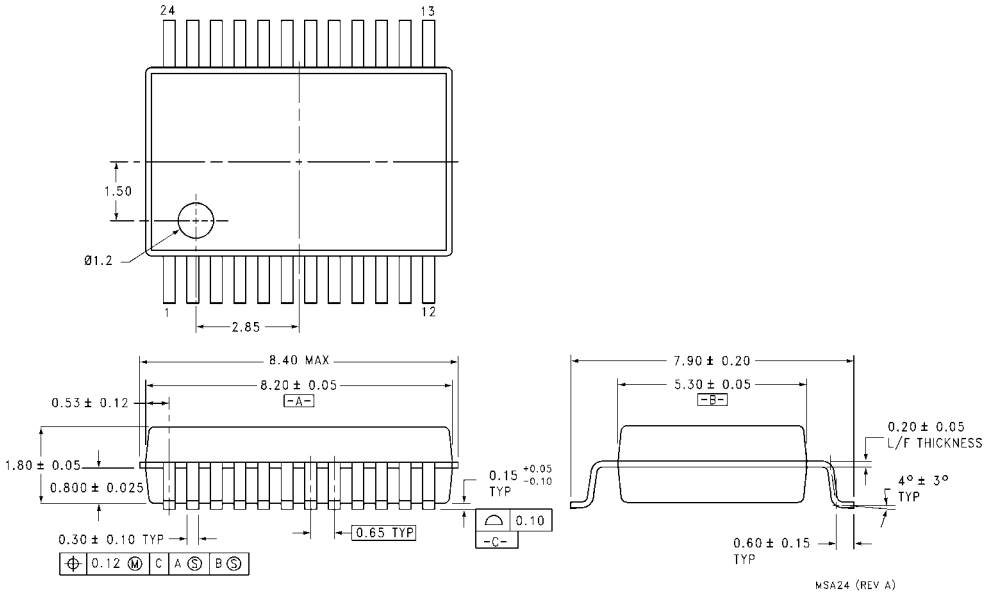
AC Operating Requirements

Symbol	Parameter	$T_A = +25°C$, $V_{CC} = +5.0V$		$T_A = -55°C$ to $+125°C$, $V_{CC} = +5.0V$		$T_A = 0°C$ to $+70°C$, $V_{CC} = +5.0V$		Units
		Min	Max	Min	Max	Min	Max	
$t_S(H)$	Setup Time, HIGH or LOW	5.0		5.0		5.0		ns
$t_S(L)$	Bus to Clock	5.0		5.0		5.0		
$t_H(H)$	Hold Time, HIGH or LOW	2.0		2.5		2.0		ns
$t_H(L)$	Bus to Clock	2.0		2.5		2.0		
$t_W(H)$	Clock Pulse Width	5.0		5.0		5.0		ns
$t_W(L)$	HIGH or LOW	5.0		5.0		5.0		

Physical Dimensions inches (millimeters) unless otherwise noted

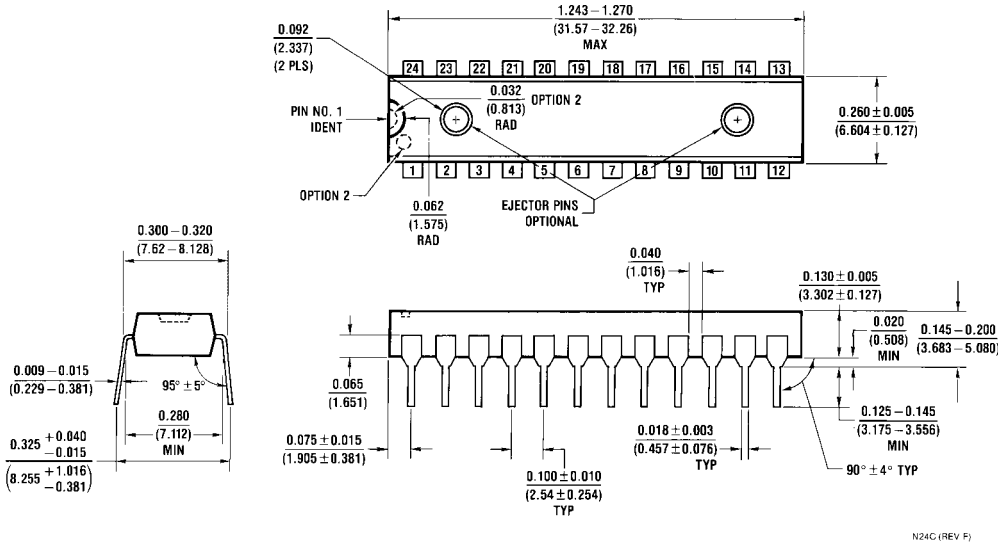


24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M24B



24-Lead Shrink Small Outline Package (SSOP), JEDEC MO-150, 5.3mm Wide
Package Number MSA24

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N24C